Magnetic Sensor (3B)

- Magnetism
- Hall Effect
- AMR Effect
- GMR Effect

Copyright (c) 2009 Young W. Lim.
Permission is granted to copy, distribute and/or modify this document under the terms of the GNU Free Documentation License, Version 1.2 or any later version published by the Free Software Foundation; with no Invariant Sections, no Front-Cover Texts, and no Back-Cover Texts. A copy of the license is included in the section entitled "GNU Free Documentation License".
Please send corrections (or suggestions) to youngwlim@hotmail.com.
This document was produced by using OpenOffice and Octave.

Magnetism

Ferro-magnetic material

• Permanent magnet

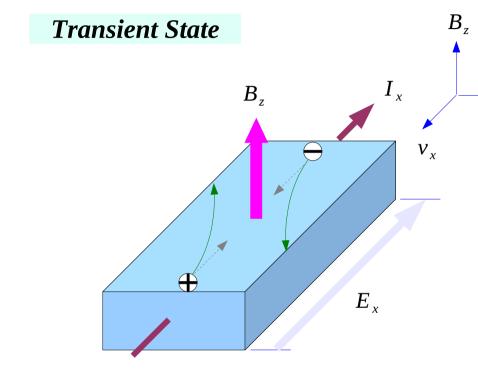
Ferri-magnetic material

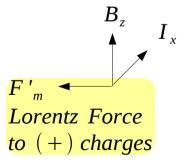
- Below Curie Temp: like ferromagnets
- Above Curie Temp: like paramagnets

Para-magnetic material

• DC Josephson: I > I_c then in the resistiv

Hall Effect (1)





Applied external magnetic field

• charges deflect

Lorentz Force

to (–) charges

- charges are accumulated
- electrical potential (E_H) are created

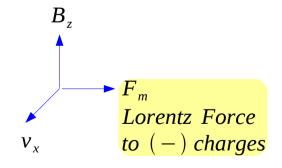
As E_H increases, new (+) and (-) charges are repelled by those previously accumulated charges. (balancing effect)

Hall Effect (2)

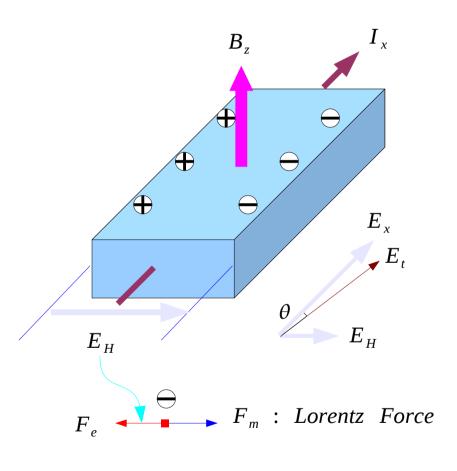
The force Fe counteracts Fm.

- F_e : due to E_H
- F_m : due to external magnetic field B_z

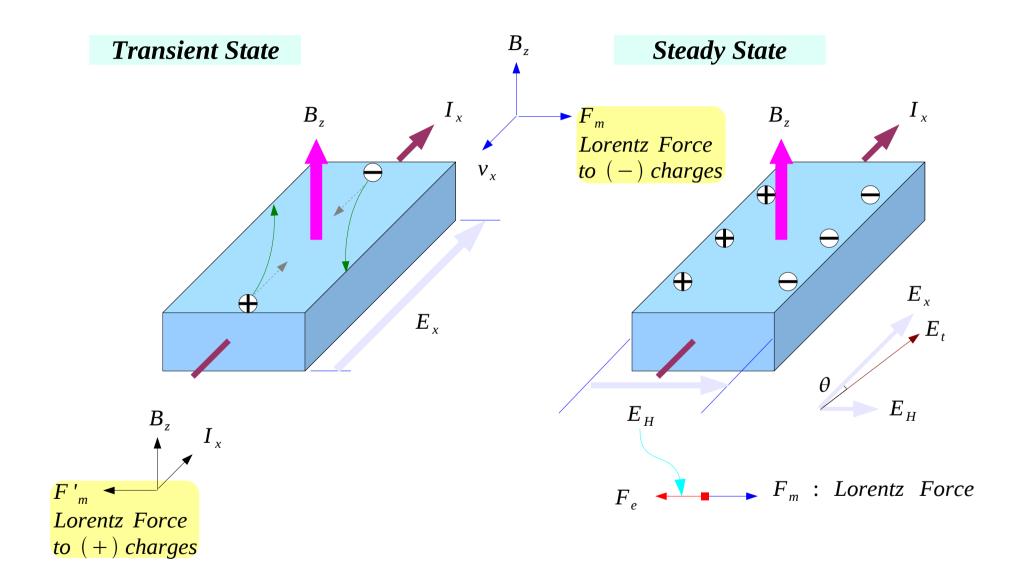
Again charges travels straight, but with the <u>Hall angle</u> θ .



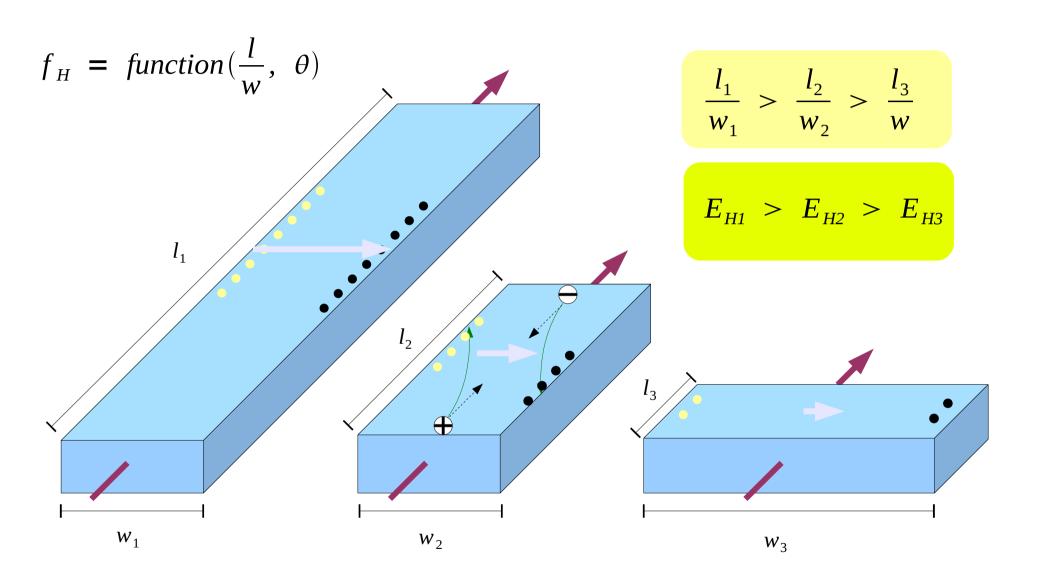
Steady State



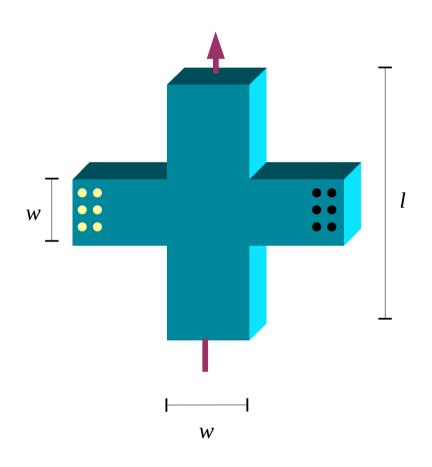
Hall Effect (3)

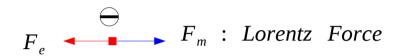


Hall Effect - Geometric Factor (1)



Hall Effect – Geometric Factor (2)





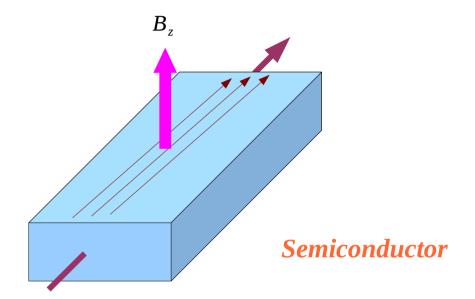
The force Fe counteracts Fm.

- F_e : due to E_H
- F_m : due to external magnetic field B_z

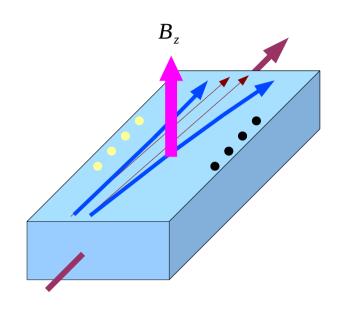
More charges are accumulated at the both ends until they repel other new charges.

Physical Magneto-resistance Effect

Ideal Case



Real Case



- Different Lorentz Force to each charge
- Different charges travel different paths
- The total length of paths is increased
- The resistance increases slightly

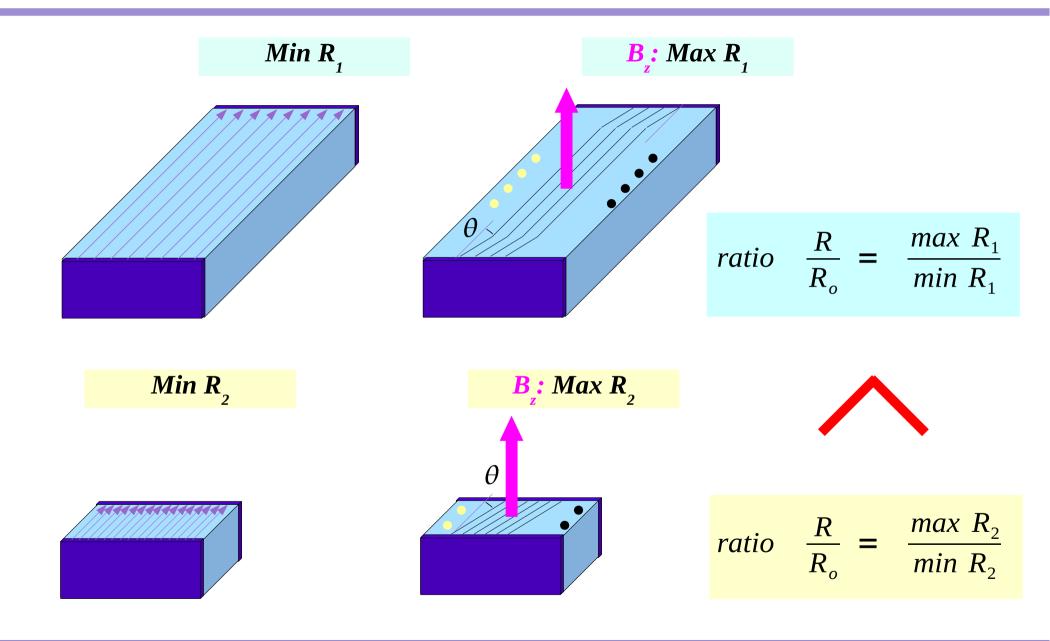
Geometrical Magneto-resistance Effect (1)

Ideal Cases

Real Cases

Metal Electrode Contact

Geometrical Magneto-resistance Effect (2)



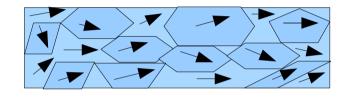
Magnetic Anisotropy (1)

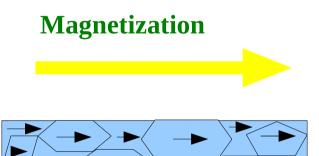
Magneto-crystalline Anisotropy

- An intrinsic property of a ferri-magnet
- Magnetization curve along different crystal directions
- Easy direction
- Hard direction
- Intermediate direction

Magnetic Anisotropy (2)



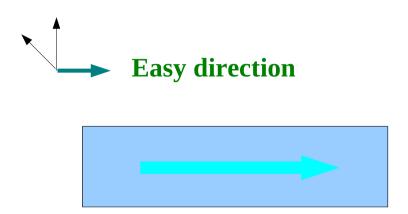




Permalloy Resistor : NiFe (ferri-magnet)



Permalloy Resistor (1)





: parallel current direction



 R_{min} : large current

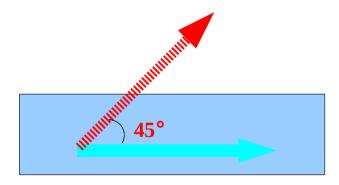
: perpendicular current direction



Permalloy Resistor (2)

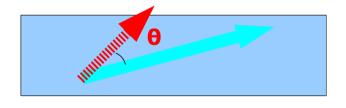


Fix the direction of current



External Magnetic Field changes

- the magnetization direction of permalloy
- the resistance
- the current



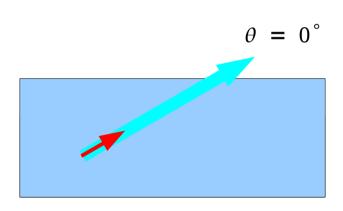


AMR Sensor (1)

The current direction is fixed

R_{max}: small current

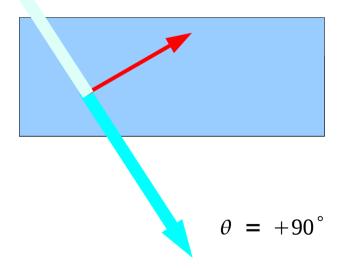
: parallel current direction



R_{min}: large current

: perpendicular current direction

$$\theta = -90^{\circ}$$



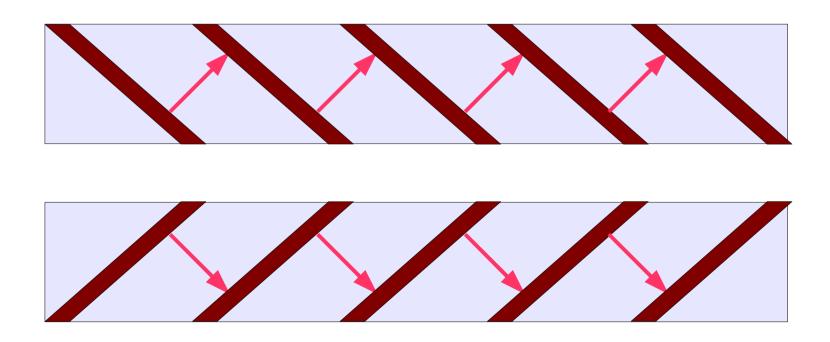
AMR Sensor (2)

How the current direction is <u>fixed</u>?

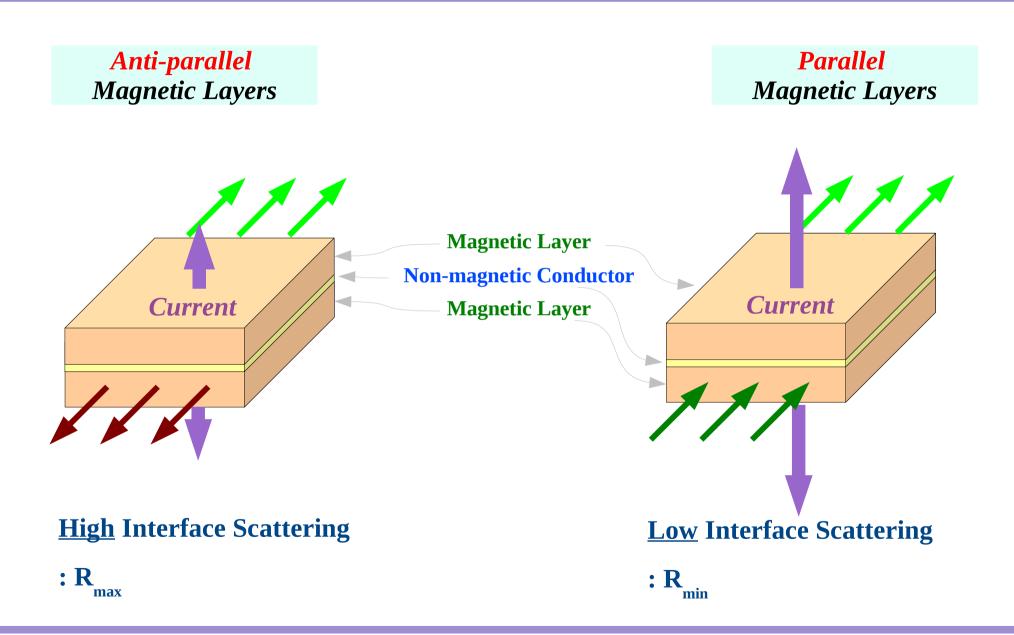


Barber Pole Biasing

: the shortest path

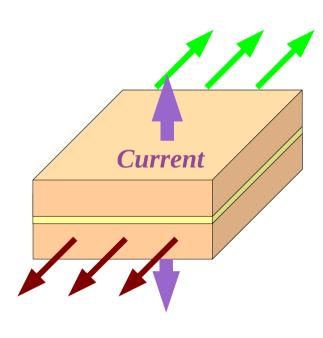


Giant Magneto-resistance Effect

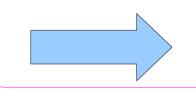


GMR Sensor

Anti-parallel Magnetic Layers Parallel
Magnetic Layers



External Magnetic Field Change



Current

Low Interface Scattering

<u>High</u> Interface Scattering

: R

:R

References

- [1] http://en.wikipedia.org/
- [2] Nam Ki Min, Sensor Electronics, Dong-il Press
- [3] http://www.sensorsmag.com/ articles